

Vishay Siliconix

P-Channel 2.5-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
- 20	0.430 at V _{GS} = - 4.5 V	- 0.72		
	0.480 at V _{GS} = - 3.6 V	- 0.68		
	0.700 at V _{GS} = - 2.5 V	- 0.56		

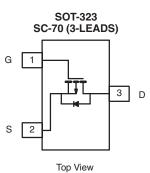
FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs
- 2.5 V Rated
- Compliant to RoHS Directive 2002/95/EC



HALOGEN

FREE Available



Marking Code

Ordering Information: Si1303DL-T1-E3 (Lead (Pb)-free) Si1303DL-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter	Symbol	5 s	Steady State	Unit		
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 12			
Constitutions Durate Outward (T 150 00)	T _A = 25 °C	– I _D	- 0.72	- 0.67	А	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 0.58	- 0.54		
Pulsed Drain Current		I _{DM}	- 2.5		А	
Continuous Diode Current (Diode Conduction) ^a		۱ _S	- 0.28	- 0.24		
Marian Dissidution	T _A = 25 °C	- P _D	0.34	0.29	W	
Maximum Power Dissipation ^a	T _A = 70 °C	'D	0.22	0.19		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 5 s	R _{thJA}	315	375	
Maximum Junction-to-Ambient ^a	Steady State		360	430	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	285	340	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•			•	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	- 0.6		- 1.4	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -20 V, V_{GS} = 0 V$			- 1	μΑ	
		V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 70 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V$, $V_{GS} = -4.5 V$	- 2.5			Α	
		V _{GS} = - 4.5 V, I _D = - 1 A		0.360	0.430	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -3.6 \text{ V}, \text{ I}_{D} = -0.7 \text{ A}$		0.400	0.480		
		$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -0.3 \text{ A}$		0.560	0.700		
Forward Transconductance ^a	9 _{fs}	V _{GS} = - 10 V, I _D = - 1 A		1.7		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 0.3 A, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			1.7	2.2		
Gate-Source Charge	Q _{gs}	V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_D = - 1 A		0.38		nC	
Gate-Drain Charge	Q _{gd}			0.63			
Turn-On Delay Time	t _{d(on)}			9	15		
Rise Time	t _r	V_{DD} = - 10 V, R _L = 10 Ω		31	45]	
Turn-Off DelayTime	t _{d(off)}	$I_D \cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		12.5	20	ns	
Fall Time	t _f			14	20]	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1 A, dI/dt = 100 A/μs		35	55]	

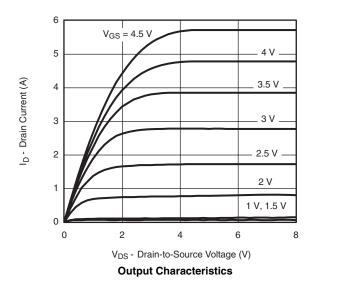
Notes:

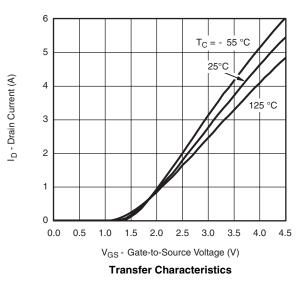
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

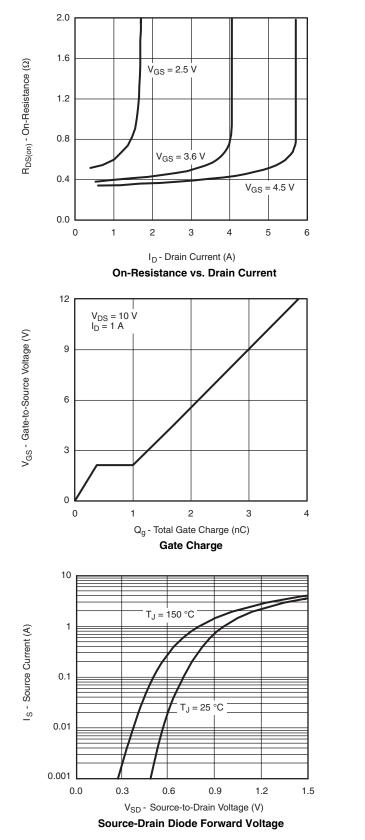


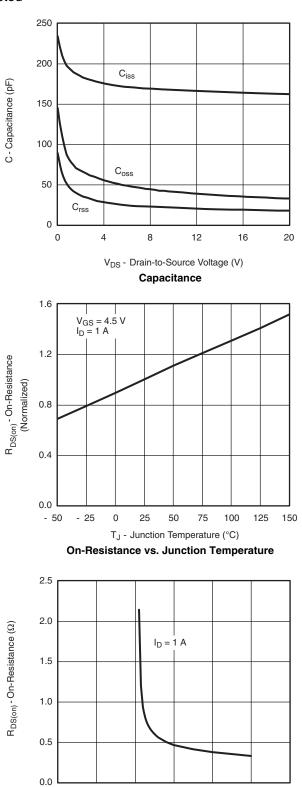




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V_{GS} - Gate-to-Source Voltage (V) On-Resistance vs. Gate-to-Source Voltage

3

4

0

1

2

5

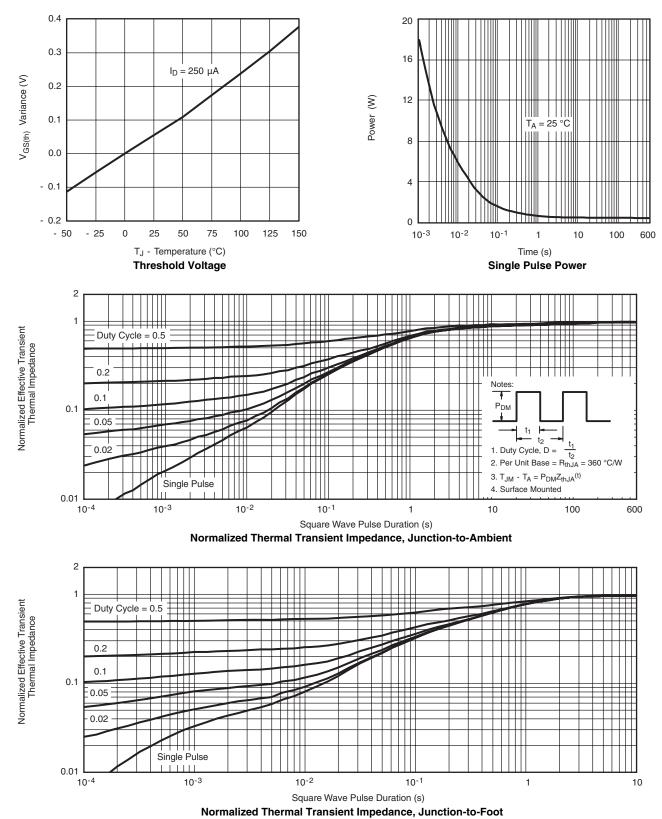
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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71075.



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